

TO-220 Plastic-Encapsulate Diodes

Schottky Barrier Rectifier

MAIN CHARACTERISTICS

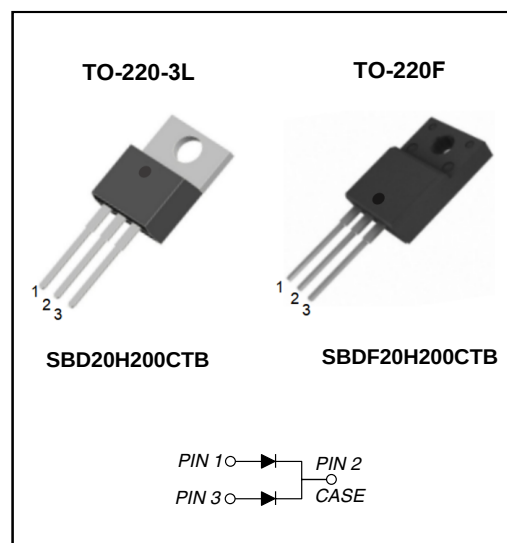
I_o	20(10×2)A
V_{RRM}	200 V
T_j	175 °C
$V_{F(typ)}$	0.67V (@ $T_j=150^{\circ}C$)

FEATURES

- Low Power Loss,High Efficiency
- Guard Ring Die Construction for Transient Protection
- High Current Capability and Low Forward Voltage Drop
- Metal Silicon Junction, Majority Carrier Conduction.
- For Use In Low Voltage,High Frequency Inverters, Free Wheeling and Polarity Protection Applications.

Mechical Data

- Case: TO-220-3L&TO-220F
- Molding compound: UL flammability classification rating 94V-0
- Terminals: Solder plated, solderable per MIL- STD-202, Method 208
- Polarity: Color band denotes cathode end



MAXIMUM RATINGS ($T_a=25^{\circ}C$ unless otherwise noted)

Symbol	Parameter	SBD		Unit
		20H200CTB	F20H200CTB	
V_{RRM}	Peak repetitive reverse voltage	200		V
V_{RWM}	Working peak reverse voltage			
V_R	DC blocking voltage			
$V_{R(RMS)}$	RMS reverse voltage	140		V
I_o	Average rectified output current	20		A
I_{FSM}	Non-Repetitive peak forward surge current (8.3ms half sine wave)	200		A
$R_{\theta Jc}$	Thermal resistance from junction to case , $T_c=25^{\circ}C$	2.0	3.0	$^{\circ}C/W$
$R_{\theta JA}$	Thermal resistance from junction to ambient	75		$^{\circ}C/W$
T_j	Junction temperature	175		$^{\circ}C$
T_{stg}	Storage temperature	-55~+175		$^{\circ}C$

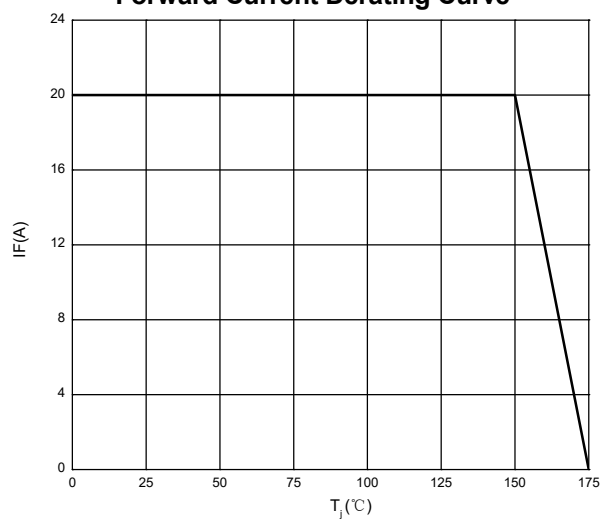
ELECTRICAL CHARACTERISTICS ($T_a=25^{\circ}C$ unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Reverse voltage	$V_{(BR)}$	$I_R=0.1mA$	200			V
Reverse current	I_R	$V_R=200V$	$T_j=25^{\circ}C$	55	500	nA
			$T_j=150^{\circ}C$	0.6		mA
Forward voltage	V_F	$I_F=5A$	$T_j=25^{\circ}C$	0.78		V
			$T_j=150^{\circ}C$	0.60		V
		$I_F=10A$	$T_j=25^{\circ}C$	0.84	0.90	V
			$T_j=150^{\circ}C$	0.67		V

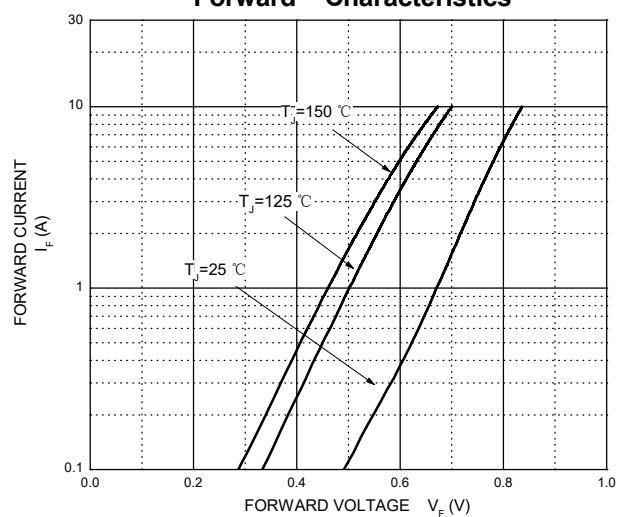
*Pulse test: pulse width $\leq 300\mu s$, duty cycles $\leq 2.0\%$.

Typical Characteristics

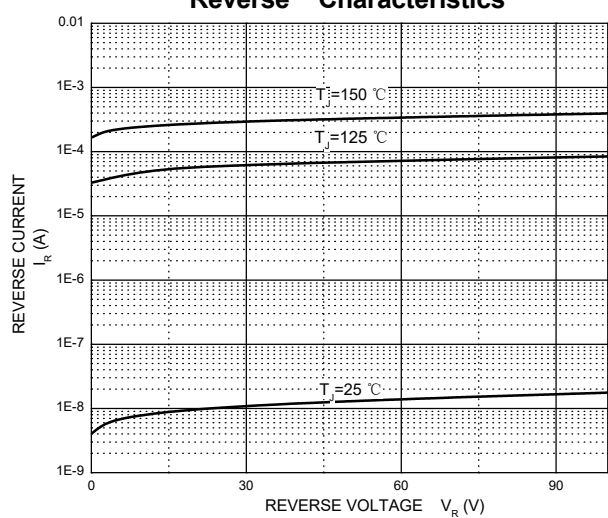
Forward Current Derating Curve



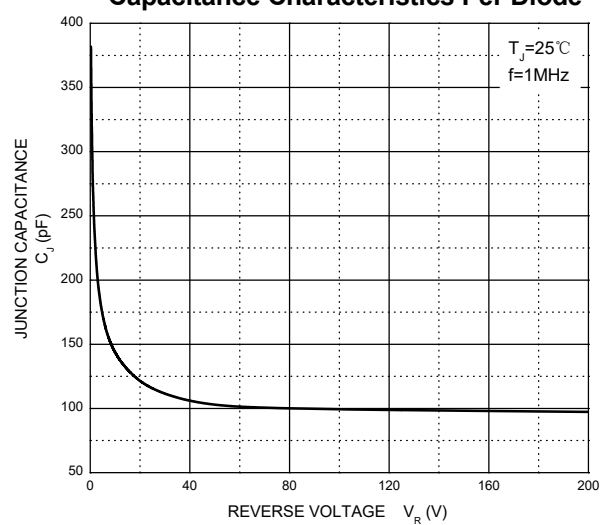
Forward Characteristics



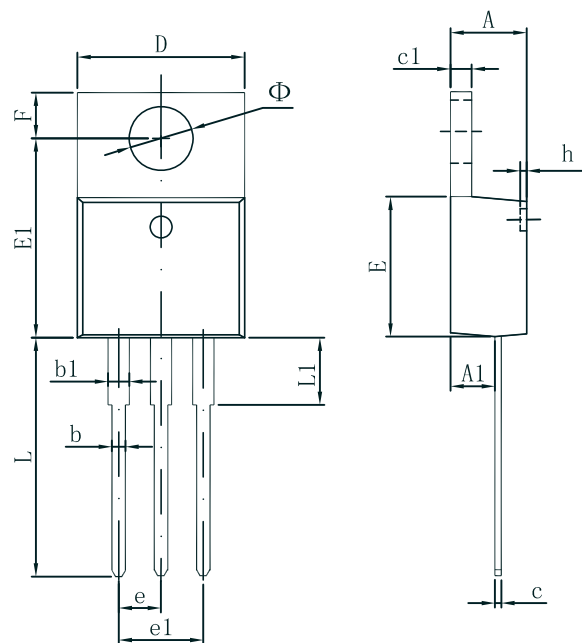
Reverse Characteristics



Capacitance Characteristics Per Diode



TO- 220- 3L Package Outline Dimensions

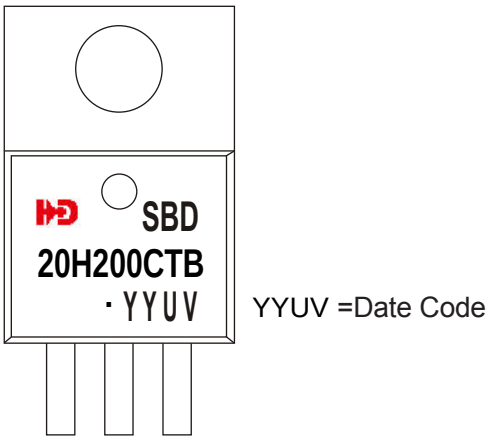


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	4.450	4.750	0.175	0.187
A1	2.520	2.820	0.099	0.111
b	0.710	0.910	0.028	0.036
b1	1.170	1.370	0.046	0.054
c	0.300	0.500	0.012	0.020
c1	1.170	1.370	0.046	0.054
D	9.830	10.330	0.387	0.407
E	8.500	8.900	0.335	0.350
E1	12.050	12.650	0.474	0.498
e	2.540 TYP		0.100 TYP	
e1	4.900	5.200	0.192	0.205
F	2.540	2.940	0.100	0.116
h	0.100 TYP		0.004 TYP	
L	13.300	13.800	0.523	0.543
L1	3.540	3.940	0.139	0.155
Φ	3.735	3.935	0.147	0.155

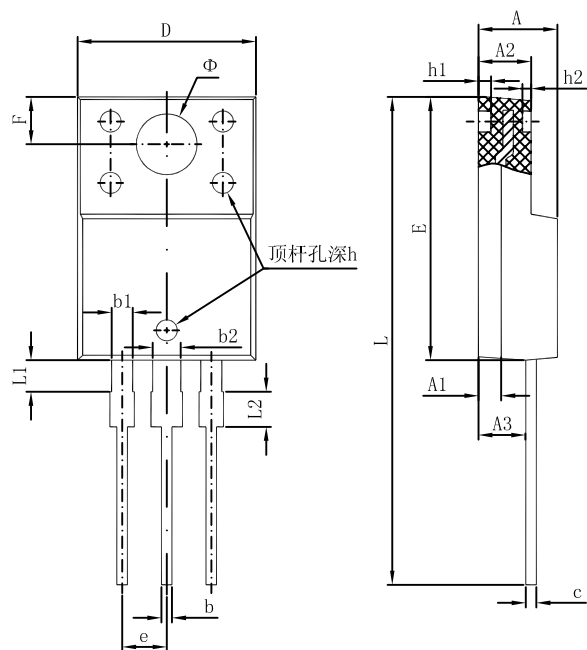
Ordering Information

Part Number	Package	Shipping Quantity
SBD20H200CTB	TO-220-3L	50pcs/Tube

Marking Diagram



TO- 220F Package Outline Dimensions

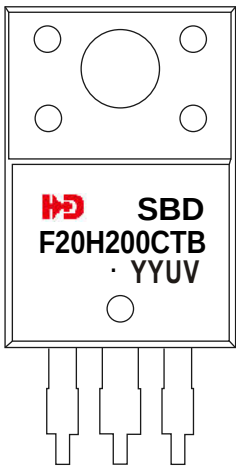


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	4.300	4.700	0.169	0.185
A1	1.300 REF.		0.051 REF.	
A2	2.600	3.200	0.102	0.126
A3	2.500	2.900	0.098	0.114
b	0.500	0.750	0.020	0.030
b1	1.100	1.350	0.043	0.053
b2	1.500	1.750	0.059	0.069
c	0.500	0.750	0.020	0.030
D	9.960	10.360	0.392	0.408
E	14.800	15.200	0.583	0.598
e	2.540 TYP.		0.100 TYP.	
F	2.700 REF.		0.106 REF.	
Φ	3.500 REF.		0.138 REF.	
h	0.000	0.300	0.000	0.012
h1	0.800 REF.		0.031 REF.	
h2	0.500 REF.		0.020 REF.	
L	28.000	28.400	1.102	1.118
L1	1.700	1.900	0.067	0.075
L2	1.900	2.100	0.075	0.083

Ordering Information

Part Number	Package	Shipping Quantity
SBDF20H200CTB	TO-220F	50pcs/Tube

Marking Diagram



YYUV =Date Code